

Over operating free-air temperature range unless otherwise noted

PARAMETER	DEFINITION	MIN	MAX	UNIT
V _{DD}	Supply voltage range	4.5	24	V
V _{INA-,INB-}	Input voltage range	-5	24	
T _J	Operating junction temperature	-40	150	°C

PARAMETER	DEFINITION	MIN	MAX	UNIT
V _{ESD}	Human Body Model (HBM), per ANSI-JEDEC-JS-001-2014 specification, all pins ⁽¹⁾	-2	+2	kV

$V_{IN}=12V$, $T_A=25^{\circ}C$.

Figure 1. UVLO vs Temperature

Figure 2. Supply current vs Temperature

Figure 3. Input Threshold vs Temperature

Figure 4. Enable Threshold vs Temperature

Figure 5 Output Rising Time vs Temperature

SCT52242

SCT52242

Overview

The SCT52242 is a dual-channel non-invertible high-speed low side driver with supporting up to 24V wide supply for both power MOSFET and IGBT. Each channel can source and sink 4A peak current along with the minimum propagation delay 13ns from input to output. The 1ns delay matching and the stackable output characteristics support higher driving capability demanding in high power converter applID 42/Lang (en-US)BDC q0.00000912 0 612 792 reeV

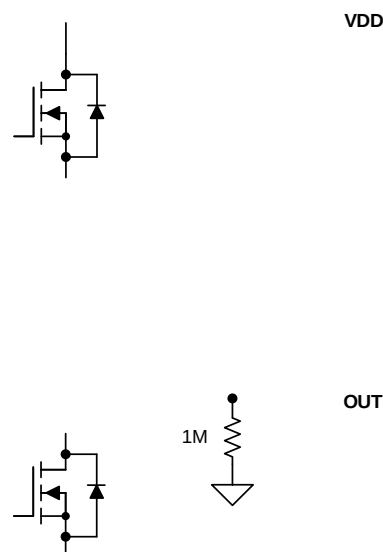


Figure 12. SCT52242 Output Stage

Stackable Output

The SCT52242 features 1ns (typical) delay matching between dual channels, which enables dual channel outputs be stackable when the driven power device required higher driving capability. By using SCT52242, the OUTA and OUTB can be connected together to provide the higher driving capability, so does the INA- and INB-. As a result, a single input signal controls the stacked output combination. To support the stackable output, each channel output stage artificially implements up to 5ns dead-time to avoid the possible shoot-through between two channels as shown Figure 13.

Due to the rising and falling threshold mismatch between INA- and INB-, cautions must be taken when implementing stackable output of OUTA and OUTB together. The maximum mismatch between INA- and INB- input threshold is up to 10mV (maximum cross temperature), as a result the allowed minimum slew rate of input logic signal is 2V/us. The following suggestions are recommended when INA- and INB- connected together and along with the OUTA and OUTB:

1. Apply the fast slew rate dv/dt on input (2 V/us or greater) to avoid the possible shoot-through between OUTA and OUTB output stage.
2. INA- and INB- must be connected as close to the pins as possible.

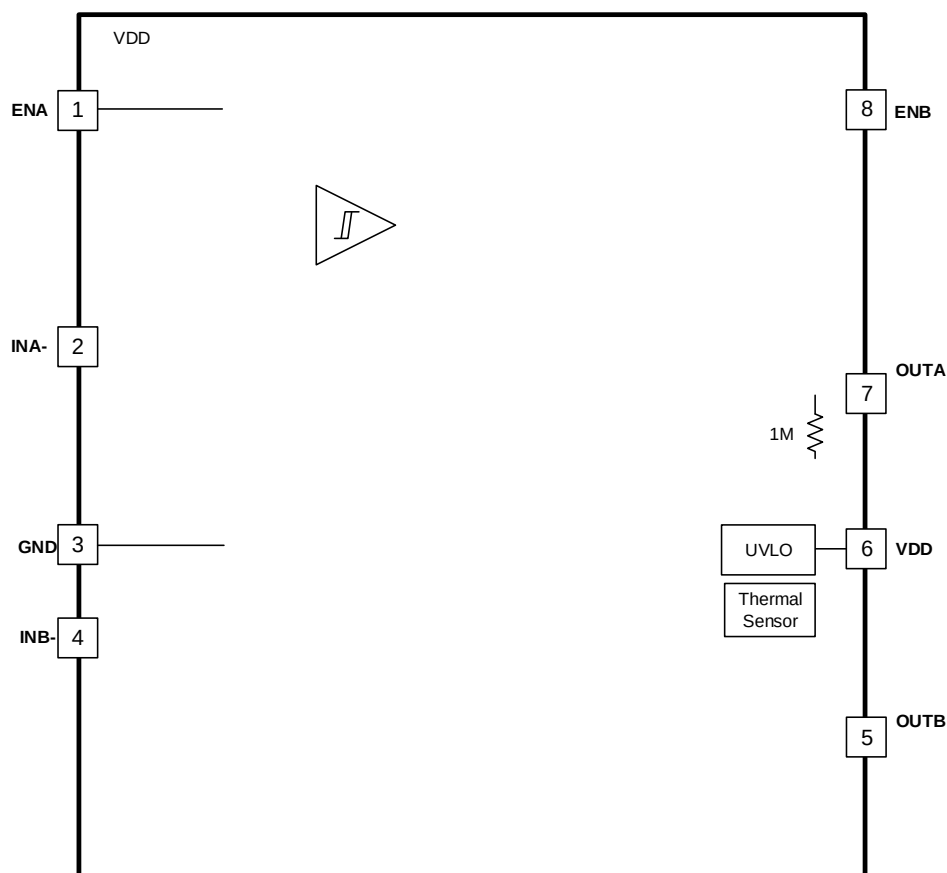


Figure 13. SCT52242 Stackable output

The Figure 14 and Figure 15 shows the stackable output with 2V/us input signal.

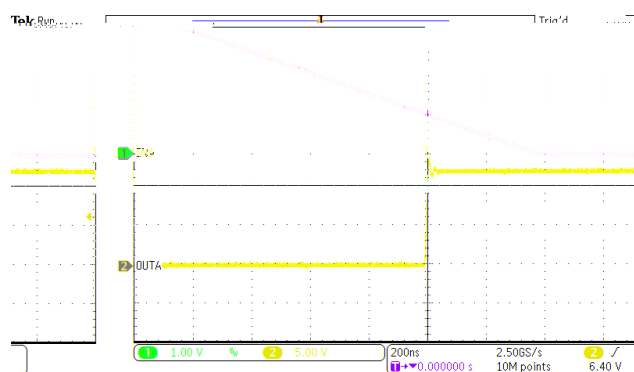


Figure 14. Driver Switching ON

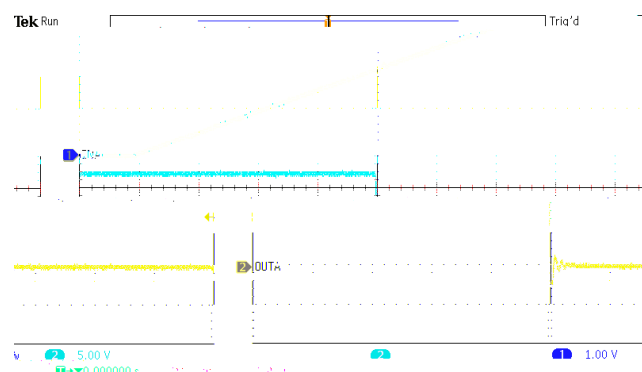


Figure 15. Driver Switching OFF

Thermal Shutdown

Once the junction temperature in the SCT52242 exceeds 170 °C, the thermal sensing circuit stops switching until the junction temperature falling below 145 °C, and the device restarts. Thermal shutdown prevents the damage on device during excessive heat and power dissipation condition.

Typical Application

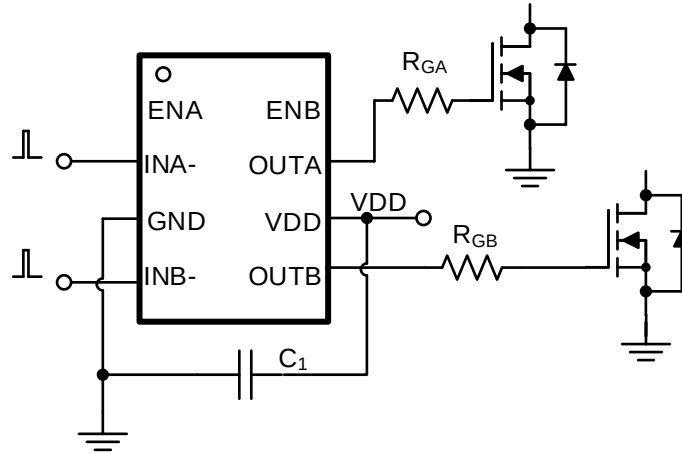


Figure 16. Dual Channel Driver Typical Application

Driver Power Dissipation

Generally, the power dissipated in the SCT52242 depends on the gate charge required of the power device (Q_g), switching frequency, and use of external gate resistors. The SCT52242 features very low quiescent currents and internal logic to eliminate any shoot-through in the output driver stage, their effect on the power dissipation within the gate driver is negligible.

For the pure capacitive load, the power loss of each channel in SCT52242 is:

(1)

Where

- V_{DD} is supply voltage
- C_{Load} is the output capacitance
- F_{SW} is the switching frequency

For the the switching load of power MOSFET, the power loss of each channel in the SCT52242 is shown in equation (2), where charging a capacitor is determined by using the equivalence $Q_g = C_{LOAD}V_{DD}$. The gate charge includes the effects of the input capacitance plus the added charge needed to swing the drain voltage of the power device as it switches between the ON and OFF states. Manufacturers provide specifications that provide the typical and maximum gate charge, in nC, to switch the device under specified conditions.

(2)

Where

- Q_g is the gate charge of the power device
- f_{sw} is the switching frequency
- V_{DD} is the supply voltage

If R_G applied between driver and gate of power device to slow down the power device transition, the power dissipation of the driver shows as below:

(3)

Where

- R_{OH} is the equivalent pull up resistance of SCT52242
- R_{OL} is the pull down resistance of SCT52242
- R_G is the gate resistance between driver output and gate of power device.

SCT52242

Application Waveforms

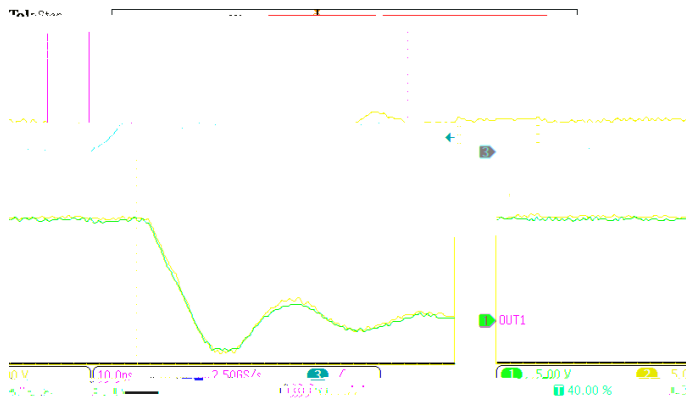


Figure 17. Driver Switching ON

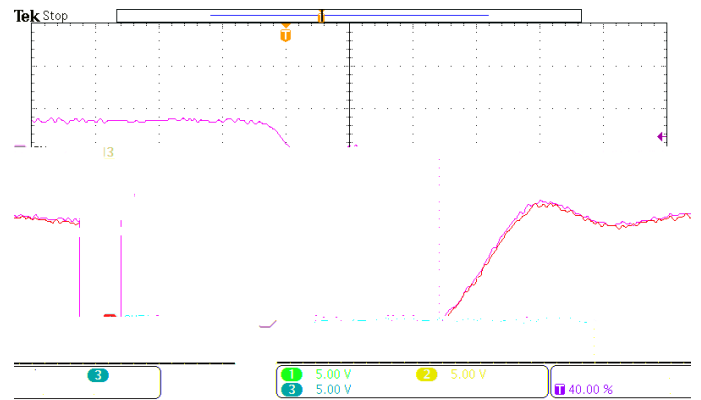


Figure 18. Driver Switching OFF

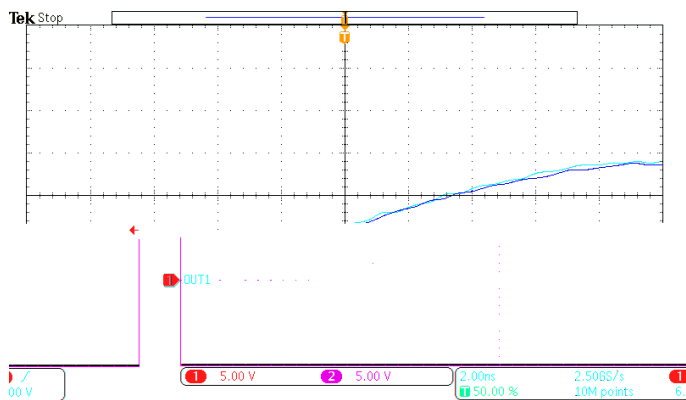


Figure 19. Delay Matching Rise

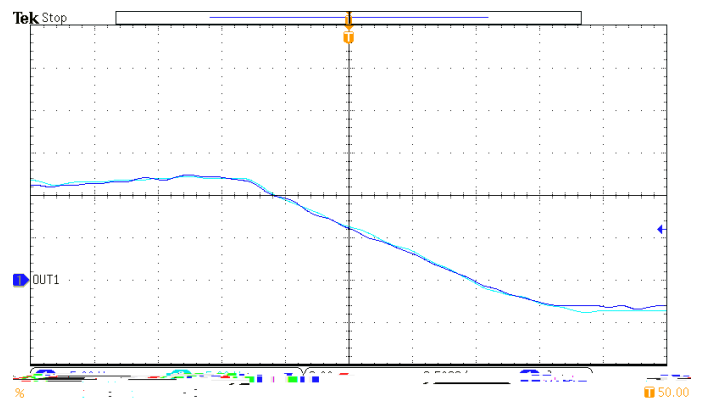


Figure 20. Delay Matching Fall

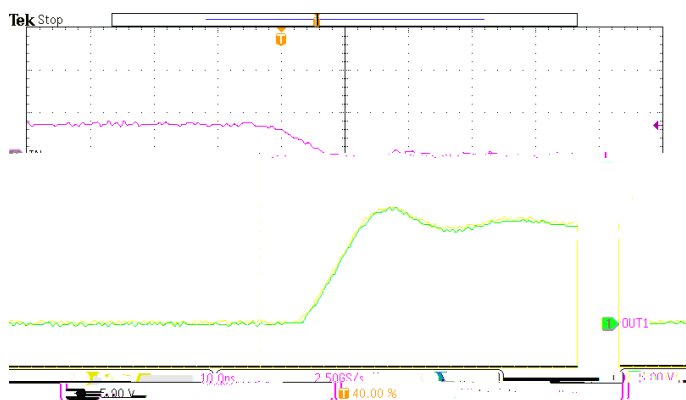


Figure 21. Stackable Output Rise

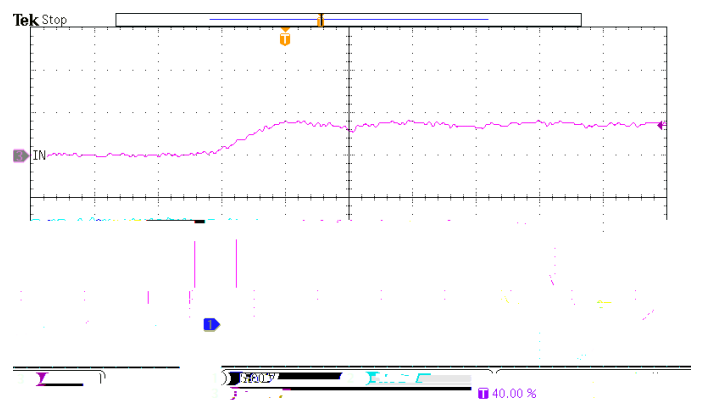
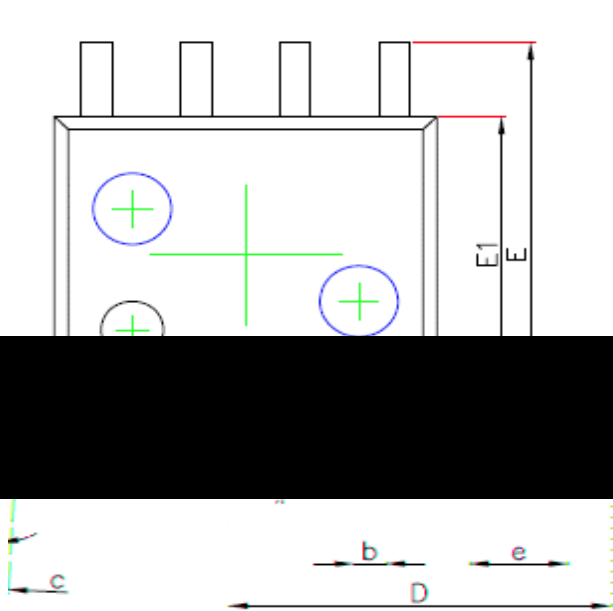


Figure 22. Stackable Output Fall

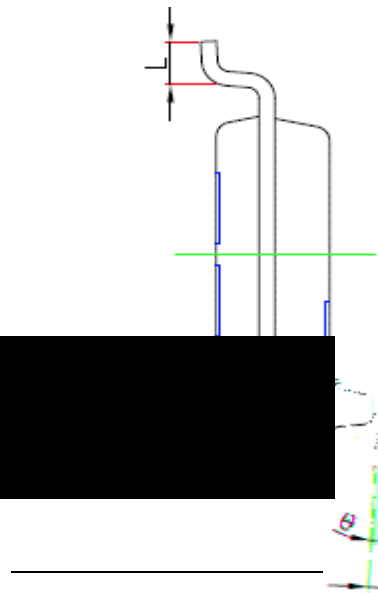
Put the SCT52242 as close as possible to the power device to minimize the gate driving loop including the driver output and power device gate.

SCT52242

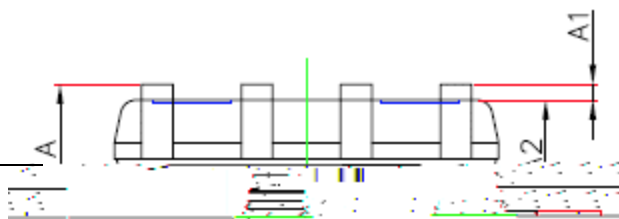
The real junction-to-ambient thermal resistance R_{ja} of the package greatly depends on the PCB type, layout, and environmental factor. Soldering the ground pin to a large ground plate enhance the thermal performance. Using more vias connects the ground plate on the top layer and bottom layer around the IC without solder mask also improves the thermal capability.



TOP VIEW



BOTTOM VIEW

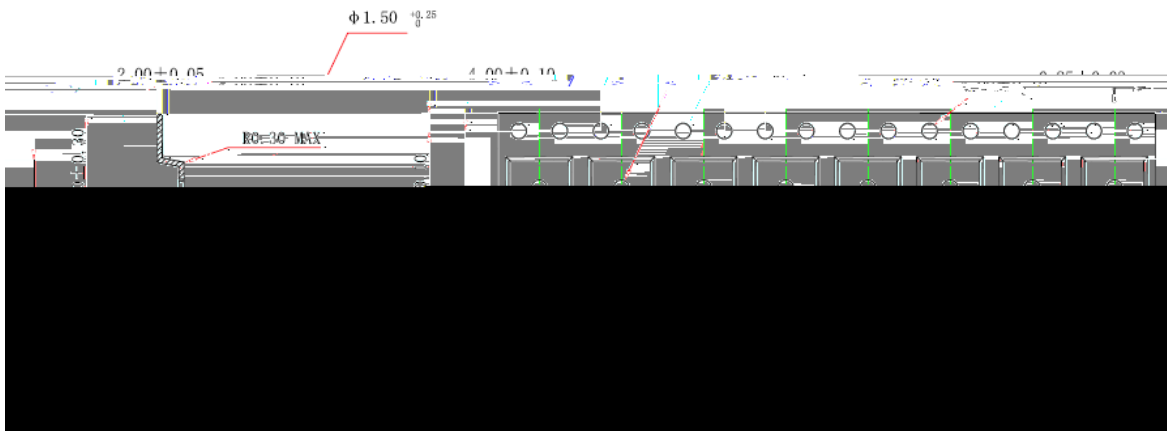


SIDE VIEW

SYMBOL	Unit: Millimeter		
	MIN	TYP	MAX

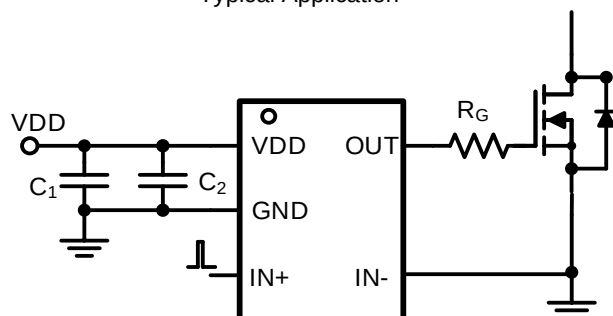
NOTE:

1. Drawing proposed to be made a JEDEC package outline MO-220 variation.
2. Drawing not to scale.
3. All linear dimensions are in millimeters.
4. Thermal pad shall be soldered on the board.
5. Dimensions of exposed pad on bottom of package do not include mold flash.
6. Contact PCB board fabrication for minimum solder mask web tolerances between the pins.



Feeding Direction →

Single Channel, Non-Inverting MOSFET Gate Drive
Typical Application



Typical Application Waveform

PART NUMBERS	DESCRIPTION	COMMENTS
SCT51240	Up to 24V Supply, 4-A Single Channel High Speed Low Side Driver	- Compatible for both Inverting and Non-inverting application - Supporting down to -5V input

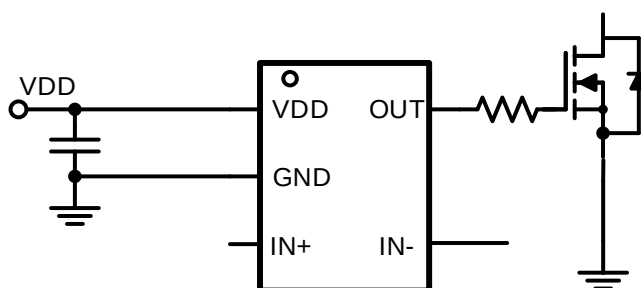


Figure 24. SCT51240 Inverting MOSFET Gate Drive Typical Application